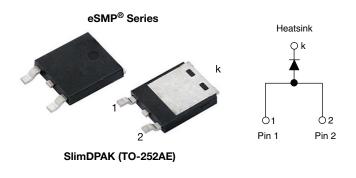
Vishay Semiconductors

www.vishay.com

Hyperfast Rectifier, 15 A FRED Pt[®]



click logo to get started

DESIGN SUPPORT TOOLS



PRIMARY CHARACTERISTICS				
I _{F(AV)}	15 A			
V _R	600 V			
V _F at I _F	1.2 V			
t _{rr} (typ.)	20 ns			
T _J max.	175 °C			
Package	SlimDPAK (TO-252AE)			
Circuit configuration	Single			

FEATURES

Meets

- Hyperfast recovery time, reduced Qrr and soft recovery
- For PFC CRM / CCM operation
- Low forward voltage drop, low power losses
- Low leakage current

MSL

COMPLIANT HALOGEN J-STD-020, FREE

RoHS

LF maximum peak of 260 °C Meets JESD 201 class 2 whisker test

level

 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

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per

TYPICAL APPLICATIONS

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters, or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating

Base PN/-M3 - halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		600	V		
Average rectified forward current	I _{F(AV)}	T _C = 140 °C	15	٨		
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	120	A		
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
Forward voltage	V	I _F = 15 A	-	1.6	2.10	
	V _F	I _F = 15 A, T _J = 150 °C	-	1.2	1.6	
Devenes la slus es summert	I _R	$V_{\rm R} = V_{\rm R}$ rated	-	-	20	
Reverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA
Junction capacitance	CT	V _R = 600 V	-	17	-	pF



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t _{rr}	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50$	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		30	-	ns
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	20	-	
Reverse recovery time		$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{RR} = 0.25 \text{ A}$		-	-	30	
		T _J = 25 °C	I _F = 15 A dI _F /dt = 500 A/μs V _R = 400 V	-	42	-	-
		T _J = 125 °C		-	90	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	7.5	-	A
		T _J = 125 °C		-	13.5	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	140	-	nC
		T _J = 125 °C		-	550	-	no

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to case	R _{thJC}		-	-	1.25	°C/W
Marking device		Case style SlimDPAK (TO-252AE)		15E\	/H06	

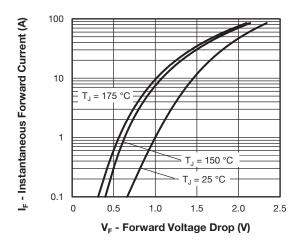


Fig. 1 - Typical Forward Voltage Drop Characteristics

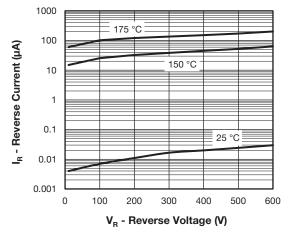


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage





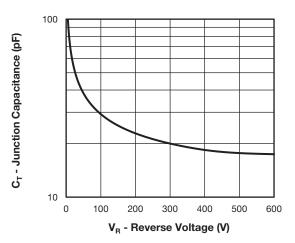


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

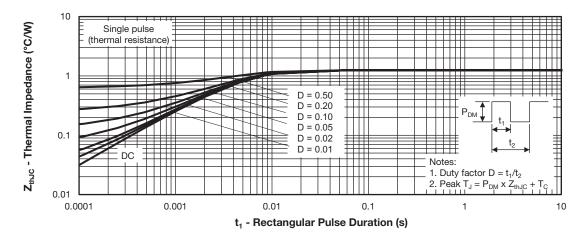
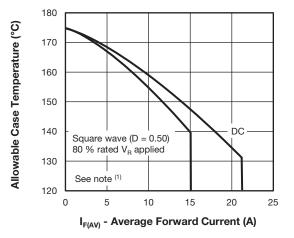
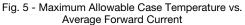


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics





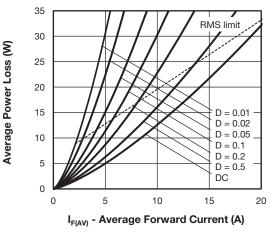


Fig. 6 - Forward Power Loss Characteristics

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} Pd = forward \ power \ loss = I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ fig. \ 6); \\ Pd_{REV} = inverse \ power \ loss = V_{R1} \ x \ I_{R} \ (1 - D); \ I_{R} \ at \ V_{R1} = rated \ V_{R} \end{array}$

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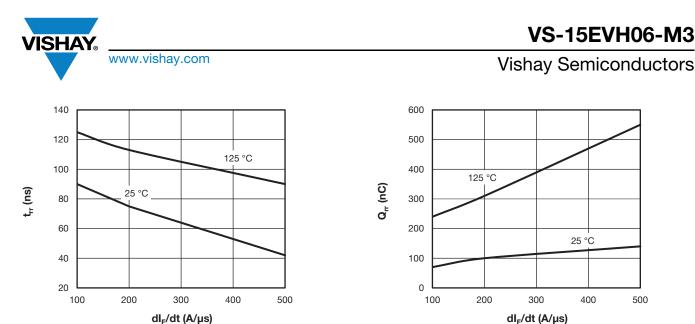


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt



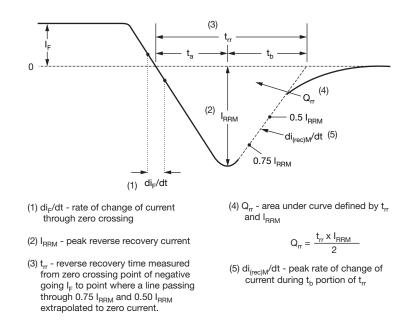
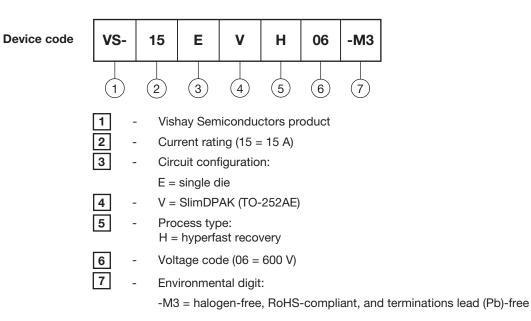


Fig. 9 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-15EVH06-M3/I	0.20	1	4500	13"diameter plastic tape and reel			

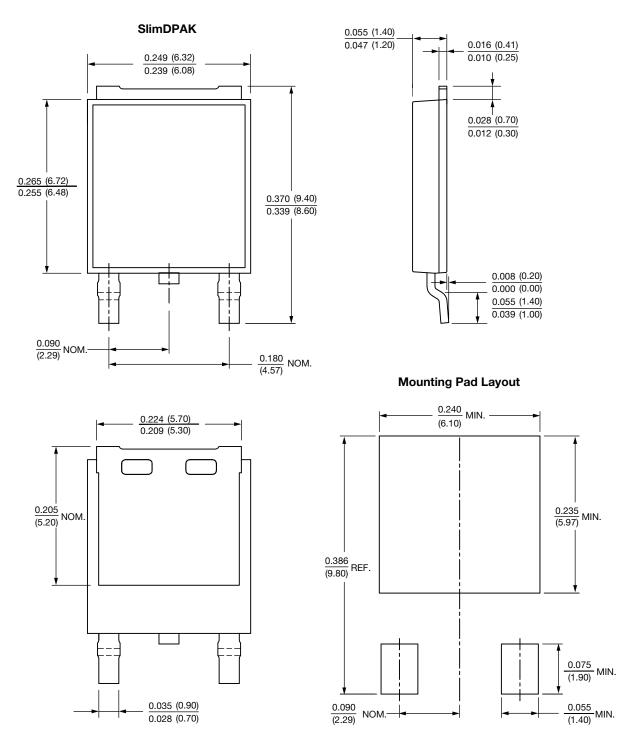
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96081</u>				
Part marking information	www.vishay.com/doc?96085			
Packaging information	www.vishay.com/doc?88869			





SlimDPAK

DIMENSIONS in inches (millimeters)





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